# **AW305A Datasheet**

# Zhuhai Jieli Technology Co.,LTD

Version 2.0

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## **Revision History**

Date	Revision	Description
2023.12.08	V1.0	Initial Release
2023.12.14	\/1 1	Update APA Characteristics
2023.12.14	V1.1	Update BT Characteristics
2024.02.22	\/1 2	Update Datasheet Format And Content
2024.03.22	V1.2	Update Pin Assignment
2024.05.13	V1.3	Update Features
2024.00.42	) / A	Update BT Transmitter characteristics
2024.08.12	V1.4	Update IC Marking Information
2025.01.17	V2.0	Update Features_Bluetooth





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## **AW305A Features**

#### **SYSTEM**

- 32bit DSP 240MHz
- ➤ Support AES128
- I-cache
- Support EMU
- On-chip SRAM 80kbyte
- Support MPU
- Built-In Flash
- 24MHz crystal oscillator
- > 32.768kHz crystal oscillator
- Internal RC oscillator,PLL

#### **DSP Audio Processing**

- SBC/SPEEX/OPUS/MP2/UMP3/MP3/MIDI/F1 A/ADPCM/A codec
- mSBC voice codec

#### **Audio**

- ➤ 1 x 16bit DAC
  - SNR 90dB
  - Noise 18uVrms
  - ❖ Sampling rate 8~96kHz
- ➤ 1 x 16bit ADC
  - ❖ SNR 95dB
  - ❖ Sampling rate 8~48kHz
- 1 x 16bit Class-D Speaker Driver
  - SNR 98dB
  - ❖ Sampling rate 32~48kHz
  - Drive speaker directly 320mW @ 8Ω
- ▶ I<sup>2</sup>S interface

#### **Bluetooth**

- ➢ BLE6.0 +2.4GHz-Proprietary (DN Q334307)
- Support AoA Transmitter
- Support long range BLE
- Maximum transmitting power 8dBm
- Receiver sensitivity
  - -95dBm @BLE-1Mbps
  - -93dBm @BLE-2Mbps
  - -99dBm @BLE-S2

-104dBm @BLE-S8

#### **Peripherals**

- > 1 x Full speed USB
- 1 x SD host controller
- ➤ 4 x Multi-function 16bit timer
- > 3 x UART intderface
- ➤ 1 x I<sup>2</sup>C Master/Slave interface
- > 3 x SPI Master/Slave interface
- > 1 x 12bit 1Msps ADC(8 Channel)
- > 15 x GPIO Support function remapping
- > 1 x CAN controller
- ➤ 6 x MCPWM
- 3 x Touchkey

#### **PMU**

- VPWR range 2.7V to 5.5V
- > IOVDD range 1.8V to 3.6V

#### Packages

➤ SSOP24

#### **Temperature**

- Operating temperature
  - TC =  $-20^{\circ}$ C to  $+85^{\circ}$ C (standard range)
  - TC =  $-40^{\circ}$ C to  $+105^{\circ}$ C (extended range)
- Storage temperature -65 °C to +150 °C

#### **Applications**

- > Bluetooth TV remote controller
- Bluetooth intercom



## 1 Block Diagram

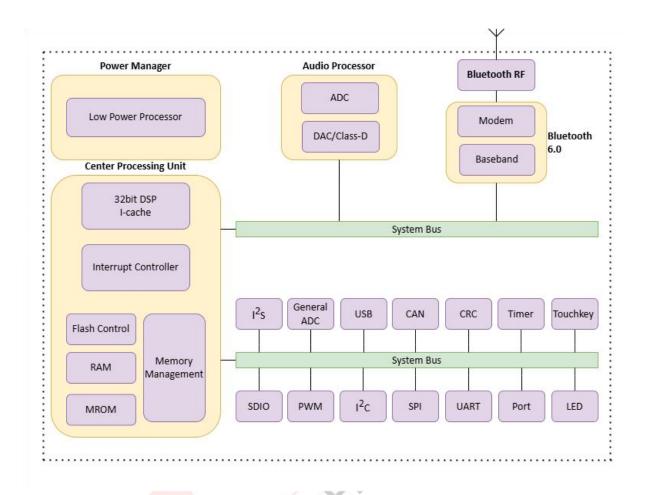


Figure 1-1 AW305A Block Diagram



## **2** Pin Definition

## 2.1 Pin Assignment

PA0         1         24         PB1           BTRF         2         23         PB2           VSS         3         22         IOVDD           VPWR         PB5/APA         PB5/APA           PA15         6         AW305A         19         PB6/APA           PA14         7         SSOP24         18         PA2           PA13         8         17         PA6         PA7           PA11         10         15         PA8           USBDM         11         14         AVSS	
--	--

Figure 2-1 AW305A Pin Assignment



## 2.2 Pin Description

Table 2-2-1 AW305A Pin Description

Pin No.	Name	Туре	IO Initial State	Description
1	PA0	1/0	15kΩ Pull-down	
2	BTRF	RF		Bluetooth RF Antenna
3	VSS	G		Ground
4	XOSCI	1		Crystal Oscillator Input
5	xosco	0		Crystal Oscillator Output
6	PA15	I/O	Z	ADC5(ADC Input Channel 5) SPI0_DIB(1)
7	PA14	I/O	Z	ADC4(ADC Input Channel 4) SPIO_DOB(0)
8	PA13	I/O	Z	ADC3(ADC Input Channel 3) SPIO_CLKB
9	PA12	I/O	Z	AINN(ADC Negative Input) SPIO_DATB(3)
10	PA11	I/O	Z	AINP(ADC Positive Input) SPIO_DATB(2)
11	USBDM	1/0	15kΩ Pull-down	ADC7(ADC Input Channel 7)
12	USBDP	1/0	15kΩ Pull-down	ADC6(ADC Input Channel 6)
13	AVSS	G	-	AUDIO Ground
14	PA8	1/0	Z	ADC2(ADC Input Channel 2) AIN_AP0(Audio ADC Positive Input)
15	PA7	1/0	Z	AIN_AP4(Audio ADC Positive Input) MICBIASC(MIC Bias Output)
16	PA6	I/O	z	AIN_AP3(Audio ADC Positive Input) AIN_AN(Audio ADC Negative Input)
17	PA5	1/0	Z	ADC1(ADC Input Channel 1)  AIN_AP2(Audio ADC Positive Input)  DAC Output
18	PA2	1/0	10kΩ Pull-up	Touch1 Hold down 0 to reset
10	PB6	1/0	Z	
19	APAN	0	Z	Class-D Speaker Driver Negative Output
20	PB5	I/O	Z	
20	APAP	0	Z	Class-D Speaker Driver Positive Output
21	VPWR	Р		Battery Input
22	IOVDD	Р		IO Power
23	PB2	I/O	Z	Touch5 32.768k Crystal Oscillator Output



Pin No.	Name	Туре	IO Initial State	Description
24	PB1	I/O	Z	Touch4 32.768k Crystal Oscillator Input

#### Note

- 1.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.
- 2.Timer, MCPWM, UART, I<sup>2</sup>C, I<sup>2</sup>S, SPI1/2, SD, CAN functions can be remapped to any I/O.

**Table 2-2-2 Pin Types Description** 

Pin Type	Description	Pin Type	Description
Р	Power	1/0	Input or Output
G	Ground	I	Input
RF	RF antenna	0	Output



## 3 Electrical Characteristics

## 3.1 Absolute Maximum Ratings

**Table 3-1 Absolute Maximum Ratings** 

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-20	+85	${\mathbb C}$
Tstg	Storage temperature	-65	+150	$^{\circ}$
VPWR	Const. Valle or	-0.3	6.0	V
IOVDD	Supply Voltage	-0.3	3.6	V
GPIO	Input voltage of GPIO (except PAO/PB5/PB6)	-0.3	3.6	V
HVTIO	Input voltage of HVT-IO (PA0/PB5/PB6)	-0.3	6.0	V

#### Note

## 3.2 ESD Ratings

**Table 3-2 ESD Ratings** 

Parameter	Тур	Test pin	Reference standard
Human Body Mode	±4kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±2kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

#### 3.3 PMU Characteristics

Table 3-3-1 PMU Characteristics under VPWR supply

	The state of the s							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
VPWR	Power supply	-	2.7		5.5	V		
Operating mod	Operating mode							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
IOVDD	Voltage output			3.0		V		
טטטט	Loading current	IOVDD=3.0V@VPWR = 3.7V			120	mA		
Low Power mo	ode							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
IOVDD	Loading current	IOVDD=3.0V@VPWR = 3.7V	-		10	mA		

Table 3-3-2 PMU Characteristics under IOVDD supply

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
IOVDD	Power supply		1.8	-	3.6	V

<sup>1.</sup>Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.



## 3.4 IO Characteristics

**Table 3-4 IO Characteristics** 

Input Chai	racteristics	Table 3-4 IO Cha				
Symbol	Parameter	Conditions	10	Min	Max	Unit
	raidineter	Conditions	PA0,PA2,PA5~PA8		IVIGA	O i iii
			PA11~PA15			
V <sub>IL</sub>	Low-Level Input Voltage	IOVDD = 3.0V	PB1,PB2,PB5,PB6	-0.3	1.4	V
VIL	Low Level input voltage	10 4 5 5 - 3.04	USBDP	0.5	1.4	·
			USBDM			
			PA2,PA5~PA8			
			PA11~PA15			
		IOVDD = 3.0V	PB1,PB2	1.7	3.3	V
		10 4 5 5 - 3.04	USBDP		3.3	
$V_{IH}$	High-Level Input Voltage		USBDM		4	
			PAO		1	
		IOVDD = 3.0V	PB5	1.7	5.5	V
		10 10 5 5 5 5 7	PB6	1.7 5.5		ľ
Output Ch	aracteristics		100			
Symbol	Parameter	Conditions	10	Т.	ур	Unit
l <sub>OL</sub>	Turumeter	Conditions			D=0)	Onic
		IOVDD = 3.0V	PA2,PA5~PA8	9(HD=1) 21(HD=2) 54(HD=3)		
	Output Current	Voutput = 0.3V	PA11~PA15			mA
		Voutput = 0.5V	PB1,PB2			
		-	PAO			
			PB5			
		IOVDD = 3.0V	PB6			mA
		Voutput = 0.3V	USBDP			
			USBDM			
			OSBDIVI	2/11	D-0)	
		10/00 - 3 0/	PA2,PA5~PA8		D=0)	
		IOVDD = 3.0V Voutput = 2.7V	PA11~PA15	9(HD=1) 21(HD=2) 54(HD=3)		mA
		Voutput – 2.7V	PB1,PB2			
	Output Current		DAG			
I <sub>OH</sub>	Output Current		PA0			
		IOVDD = 3.0V	PB5		o	.a. A
		Voutput = 2.7V	PB6		8	mA
			USBDP			
Intoves LD	neistanes Characteristics		USBDM			
	esistance Characteristics	Conditions	10	-	100	l lmit
Symbol	Parameter	Conditions	IO DAG DAG DAG		yp	Unit
		10/10- 2.5	PA0,PA2,PA5~PA8		PU=1)	_
$R_{pu}$	Pull-up Resistance	IOVDD = 3.0V	PA11~PA15		PU=2)	Ω
			PB1,PB2,PB5,PB6	1M(F	PU=3)	



		IOVDD = 3.0V	USBDP	1.5k	Ω
		IOVDD = 3.0V	USBDM	180k	Ω
Symbol	Parameter	Conditions	10	Тур	Unit
		PA0,PA2,PA5~PA8	10k(PD=1)		
	Pull-down Resistance	IOVDD = 3.0V	PA11~PA15	100k(PD=2)	Ω
$R_{pd}$			PB1,PB2,PB5,PB6	1M(PD=3)	
			USBDP	451.	0
		IOVDD = 3.0V	USBDM	15k	Ω

#### Note

1.Internal pull-up/pull-down resistance accuracy  $\pm 20\%$ .

## 3.5 Audio DAC Characteristics

**Table 3-5 Audio DAC Characteristics** 

Parameter	Conditions	Min	Тур	Max	Unit
Resolution	-		16		bits
Output Sample Rate	-	8	-	96	kHz
	Single-ended Mode	·//			
	Fin=1kHz@0dBFS	/ 1			
SNR	Fs=44.1kHz	4	90		dB
	B/W=20Hz~20kHz A-Weighted	.0"			
	Load=100kΩ				
	Single-ended Mode				
	Fin=1kHz@-60dBFS				
Dynamic Range	Fs=44.1kHz		90		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=100kΩ				
	Single-ended Mode				
	Fin=1kHz@0dBFS				dB
THD+N	Fs=44.1kHz		-83		
	B/W=20Hz~20kHz A-Weighted				
	Load=100kΩ				
	Single-ended Mode				
Noise Floor	B/W=20Hz~20kHz A-Weighted		18		uVrms
	Load=100kΩ				
	Single-ended Mode				
	Fin=1kHz@0dBFS				
Man Amenitanda	Fs=44.1kHz		0.6		Maria
Max Amplitude	B/W=20Hz~20kHz A-Weighted	0.6			Vrms
	Load=100kΩ				
	THD+N<0.1%				



## 3.6 Audio ADC Characteristics

**Table 3-6 Audio ADC Characteristics** 

Parameter	Conditions	Min	Тур	Max	Unit
Resolution			16		bits
Input Sample Rate		8		48	kHz
	Differential Input Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz		95		dB
	B/W=20Hz~20kHz A-Weighted				
CNID	ADC Gain=0dB				
SNR	Single-ended Input Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz		91		dB
	B/W=20Hz~20kHz A-Weighted		4//		
	ADC Gain=0dB				
	Differential Input Mode				
	Fin=1kHz@-60dBFS				
	Fs=44.1kHz	<u>-</u> -	95		dB
	B/W=20Hz~20kHz A-Weighted	7.5			
Dynamic Range	ADC Gain=0dB	- W			
	Single-ended Input Mode	0			
	Fin=1kHz@-60dBFS				
	Fs=44.1kHz		91		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC Gain=0dB				
	Differential Input Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz		-85		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC Gain=0dB				
THD+N	Single-ended Input Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz		-80		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC Gain=0dB				
Analogue Gain		-6		21	dB
	Differential Input Mode				
	ADC Gain=0dB		2		Vrms
Max Input Level	Single-ended Input Mode				
	ADC Gain=0dB		1		Vrms



## **3.7 Class-D Speaker Driver Characteristics**

Table 3-7 Class-D Speaker Driver Characteristics under HPVDD 3.7V

Parameter	Conditions	Min	Тур	Max	Unit
	Differential Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz		98		dB
	B/W=20Hz~20kHz A-Weighted				
CNID	Load=10kΩ				
SNR	Differential Mode				
	Fin=1kHz@0dBFS				
	Fs=44.1kHz	>	98		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=8Ω				
	Differential Mode		4///	1	
	Fin=1kHz@0dBFS			(1)	
	Fs=44.1kHz	-	-73		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=10kΩ		OX		
THD+N	Differential Mode	/	2		
	Fin=1kHz@0dBFS				
	Fs=44.1kHz	(J.)	-37		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=8Ω				
	Differential Mode				
	B/W=20Hz~20kHz A-Weighted		30		uVrms
	Load=10kΩ				
Noise Floor	Differential Mode				
	B/W=20Hz~20kHz A-Weighted		20		uVrms
	Load=8Ω				
	Differential Mode				
	Fin=1kHz@-60dBFS				
	Fs=44.1kHz		88		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=10kΩ				
Dynamic Range	Differential Mode				
	Fin=1kHz@-60dBFS				
	Fs=44.1kHz		88		dB
	B/W=20Hz~20kHz A-Weighted				
	Load=8Ω				



## 3.8 12bit ADC Characteristics

**Table 3-8 12bit ADC Characteristics** 

Parameter	Conditions	Min	Тур	Max	Unit
AVDD(ADC Supply Voltage)	AVDD=IOVDD	1.8	3	3.3	V
f <sub>ADC</sub> (ADC Clock Frequency)		0.25		14	MHz
Ts(ADC Sampling Time)		1.5			1/f <sub>ADC</sub>
ADC Conversion Time	Including Sampling Time	8		14	1/f <sub>ADC</sub>
ADC Input Voltage Range		0		AVDD	V
ADC Internal Sample and Hold Capacitor			5		pF
Sampling Switch Resistance				1	kΩ
Estamal landt landa dan a	Ts=1.5/f <sub>ADC</sub>			1.5	kΩ
External Input Impedance	Ts>=50/f <sub>ADC</sub>		7	50	kΩ
ADC Resolution	Programmable	6	12	12	bit
INL	AVDD=3V, f <sub>ADC</sub> =14MHz		±2		LSB
DNL	AVDD=3V, f <sub>ADC</sub> =14MHz		±1		LSB
ADC Offset Error	AVDD=3V, f <sub>ADC</sub> =14MHz		3	<del>-</del>	LSB
Gain Error	AVDD=3V, f <sub>ADC</sub> =14MHz		3		LSB
Current Consumption in Conversion Mode	Single-ended, f <sub>ADC</sub> =14MHz	/	350		uA

## 3.9 BT Characteristics

#### 3.9.1 Transmitter

**Table 3-9-1 Transmitter characteristics** 

Parameter	Conditions	Min	Тур	Max	Unit
Maximum RF Transmit Power	BLE-1Mbps		0	8	dBm

#### 3.9.2 Receiver

**Table 3-9-2 Receiver characteristics** 

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity	BLE-1Mbps		-95		dBm
	BLE-2Mbps	-93	-92		dBm
	BLE-S2	-99	-98		dBm
	BLE-S8	-104	-103		dBm



## 4 Package Information

## 4.1 SSOP24

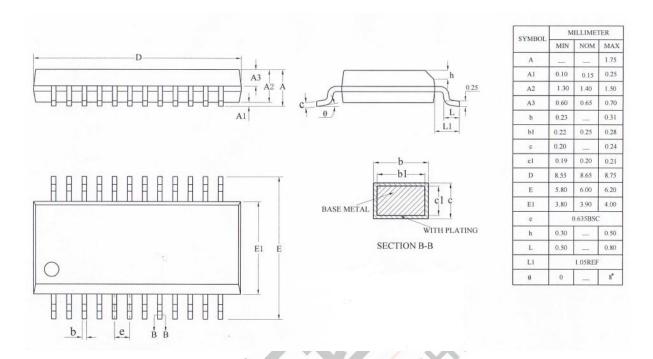


Figure 4-1 AW305A Package



## 5 IC Marking Information

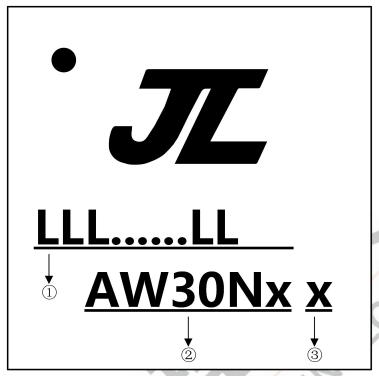


Figure 5-1 AW305A Package Outline

- 1 LLL.....LL Production Batch
- 2 AW30Nx Chip Model
- (3) x Built-in flash size
  - 0 No Flash Memory
  - 2 2Mbit Flash
  - 4 4Mbit Flash



## 6 Solder-Reflow Condition

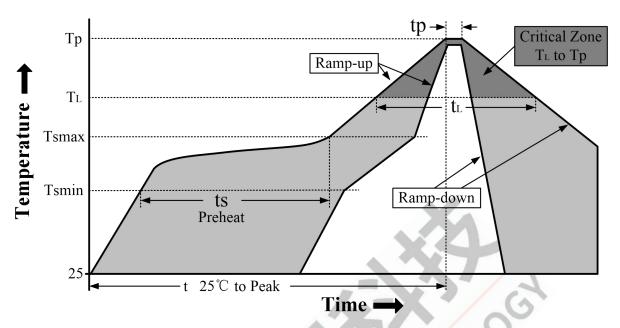


Figure 6-1 Classification Reflow Profile

**Table 6-1 Classification Profiles** 

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
	Temperature Min (T <sub>smin</sub> )	100℃	150℃
Preheat/Soak	Temperature Max (T <sub>smax</sub> )	150°C	200℃
	Time (ts) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds	60-180 seconds
Average ramp-	up rate (T <sub>smax</sub> to T <sub>p</sub> )	3°C/second max	3℃/second max
Liquidus temperature (T <sub>L</sub> )		183℃	<b>217</b> ℃
Time (t <sub>L</sub> ) maintained <mark>above T</mark> L		60-150 seconds	60-150 seconds
Peak package body temperature (Tp)		See Table 6-2	See Table 6-3
Time within 5℃ of actual		10-30 seconds	20-40 seconds
Peak Temperature (tp) <sup>2</sup>		10-30 seconds	20-40 seconds
Ramp-down rate (Tp to TL)		6℃/second max	6℃/second max
Time 25℃ to p	eak temperature	6 minutes max	8 minutes max

#### Note

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2. Time within 5  $^{\circ}$ C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" and "user" maximum.

**Table 6-2 SnPb Classification Temperature** 

Package	Volume mm³	Volume mm <sup>3</sup>
Thickness	< 350	≥ 350
<2.5 mm	240 +0/-5℃	225 +0/-5°C
≥2.5 mm	225 +0/-5℃	225 +0/-5℃



**Table 6-3 Pb-free - Classification Temperature** 

Package	Volume mm³	Volume mm³	Volume mm <sup>3</sup>
Thickness	< 350	350 - 2000	> 2000
< 1.6mm	260℃	260℃	<b>260</b> ℃
1.6 mm - 2.5mm	260℃	250℃	245℃
> 2.5mm	250℃	245℃	245℃

#### Note

1.\*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0  $^{\circ}$ C.For example 260  $^{\circ}$ C+0  $^{\circ}$ C) at the rated MSL level.

